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MC10113

Quad Exclusive OR Gate

The MC10113 is a quad Exclusive OR gate, with an enable common to all four gates. The outputs may be wire–ORed together to perform a 4–bit comparison function (A = B). The enable is active low.

- P_D = 175 mW typ/pkg (No Load)
- t_{pd} = 2.5 ns typ
- t_r, t_f = 2.0 ns typ (20%–80%)

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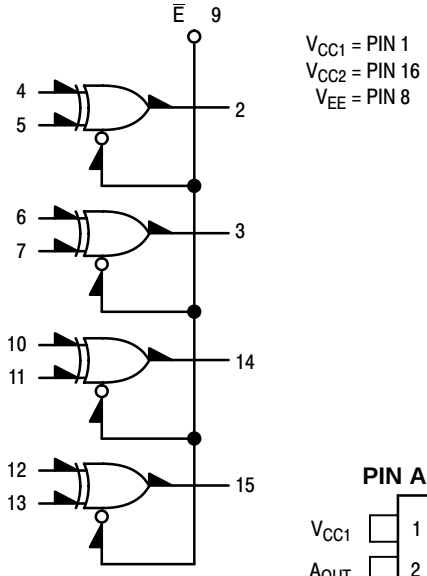
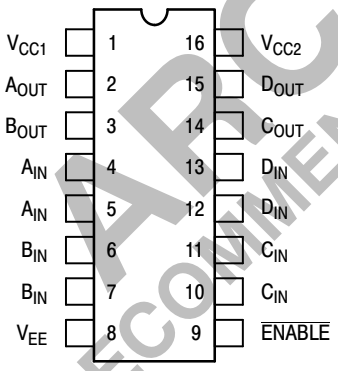
LOGIC DIAGRAM



V_{CC1} = PIN 1
V_{CC2} = PIN 16
V_{EE} = PIN 8

DIP PIN ASSIGNMENT

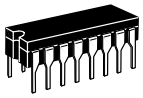


Pin assignment is for Dual–in–Line Package.
For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).

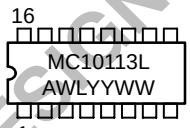
TRUTH TABLE

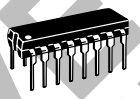
IN		$\overline{E}$	OUTPUT
L	L	L	L
L	H	L	H
H	L	L	H
H	H	L	L
X	X	H	L

MARKING DIAGRAMS

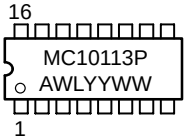


CDIP–16
L SUFFIX
CASE 620

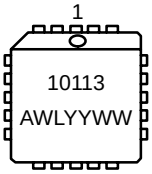




PDIP–16
P SUFFIX
CASE 648



PLCC–20
FN SUFFIX
CASE 775



A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MC10113L	CDIP–16	25 Units / Rail
MC10113P	PDIP–16	25 Units / Rail
MC10113FN	PLCC–20	46 Units / Rail

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Pin Under Test	Test Limits							Unit
			–30°C		+25°C			+85°C		
			Min	Max	Min	Typ	Max	Min	Max	
Power Supply Drain Current	I_E	8		46			42		46	mAdc
Input Current	I_{inH}	4,7,10,13 5,6,11,12 9		425 350 870			265 220 545		265 220 545	µAdc
	I_{inL}	*	0.5		0.5			0.3		µAdc
Output Voltage Logic 1	V_{OH}	2 3 14 15	–1.060 –1.060 –1.060 –1.060	–0.890 –0.890 –0.890 –0.890	–0.960 –0.960 –0.960 –0.960		–0.810 –0.810 –0.810 –0.810	–0.890 –0.890 –0.890 –0.890	–0.700 –0.700 –0.700 –0.700	Vdc
Output Voltage Logic 0	V_{OL}	2 3 14 15	–1.890 –1.890 –1.890 –1.890	–1.675 –1.675 –1.675 –1.675	–1.850 –1.850 –1.850 –1.850		–1.650 –1.650 –1.650 –1.650	–1.825 –1.825 –1.825 –1.825	–1.615 –1.615 –1.615 –1.615	Vdc
Threshold Voltage Logic 1	V_{OHA}	2 3 14 15	–1.080 –1.080 –1.080 –1.080		–0.980 –0.980 –0.980 –0.980			–0.910 –0.910 –0.910 –0.910		Vdc
Threshold Voltage Logic 0	V_{OLA}	2 3 14 15		–1.655 –1.655 –1.655 –1.655			–1.630 –1.630 –1.630 –1.630		–1.595 –1.595 –1.595 –1.595	Vdc
Switching Times (50Ω Load)					Min	Typ	Max			ns
Propagation Delay	t_{4+2+}	2	1.1	4.7	1.3	2.6	4.5	1.3	5.0	
	t_{4-2-}	2	1.1	4.7	1.3	2.6	4.5	1.3	5.0	
	t_{9+2-}	2	1.3	5.2	1.5	3.4	5.0	1.5	5.5	
	t_{9-2+}	2	1.3	5.2	1.5	3.4	5.0	1.5	5.5	
Rise Time (20 to 80%)	t_{2+}	2	1.1	4.2	1.1	2.5	3.9	1.1	4.4	
Fall Time (20 to 80%)	t_{2-}	2	1.1	4.2	1.1	2.5	3.9	1.1	4.4	

* Individually test each input applying V_{IH} or V_{IL} to input under test.

ELECTRICAL CHARACTERISTICS (continued)

@ Test Temperature	V_{IHmax}	V_{ILmin}	V_{IHAmin}	V_{ILAmax}	V_{EE}
	TEST VOLTAGE VALUES (Volts)				
–30°C	–0.890	–1.890	–1.205	–1.500	–5.2
+25°C	–0.810	–1.850	–1.105	–1.475	–5.2
+85°C	–0.700	–1.825	–1.035	–1.440	–5.2

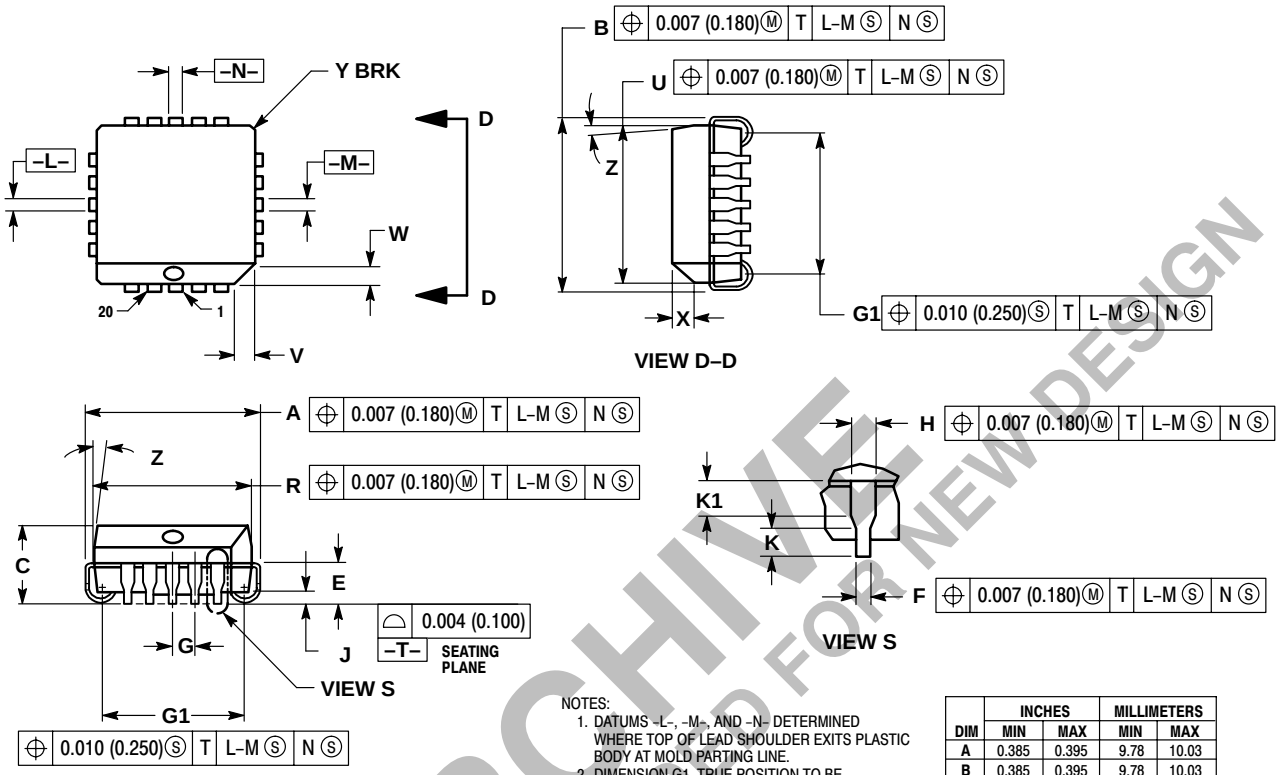
Characteristic	Symbol	Pin Under Test	TEST VOLTAGE APPLIED TO PINS LISTED BELOW					(V_{CC}) Gnd
			V_{IHmax}	V_{ILmin}	V_{IHAmin}	V_{ILAmax}	V_{EE}	
Power Supply Drain Current	I_E	8					8	1, 16
Input Current	I_{inH}	4,7,10,13	*				8	1, 16
		5,6,11,12	*				8	1, 16
		9	9				8	1, 16
	I_{inL}	*		*			8	1, 16
Output Voltage Logic 1	V_{OH}	2	4				8	1, 16
		3	7				8	1, 16
		14	11				8	1, 16
		15	13				8	1, 16
Output Voltage Logic 0	V_{OL}	2		4			8	1, 16
		3		7			8	1, 16
		14		11			8	1, 16
		15		13			8	1, 16
Threshold Voltage Logic 1	V_{OHA}	2			4		8	1, 16
		3			6		8	1, 16
		14			10		8	1, 16
		15			12		8	1, 16
Threshold Voltage Logic 0	V_{OLA}	2				5	8	1, 16
		3				7	8	1, 16
		14				11	8	1, 16
		15				13	8	1, 16
Switching Times (50Ω Load)			**+1.11V**		**Pulse In**	**Pulse Out**	**–3.2 V**	**+2.0 V**
Propagation Delay	t_{4+2+}	2			4	2	8	1, 16
	t_{4-2-}	2			4	2	8	1, 16
	t_{9+2-}	2	4		9	2	8	1, 16
	t_{9-2+}	2	4		9	2	8	1, 16
Rise Time (20 to 80%)	t_{2+}	2			4	2	8	1, 16
Fall Time (20 to 80%)	t_{2-}	2			4	2	8	1, 16

* Individually test each input applying V_{IH} or V_{IL} to input under test.

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50–ohm resistor to –2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the same manner.

PACKAGE DIMENSIONS

PLCC–20
FN SUFFIX
PLASTIC PLCC PACKAGE
CASE 775–02
ISSUE C

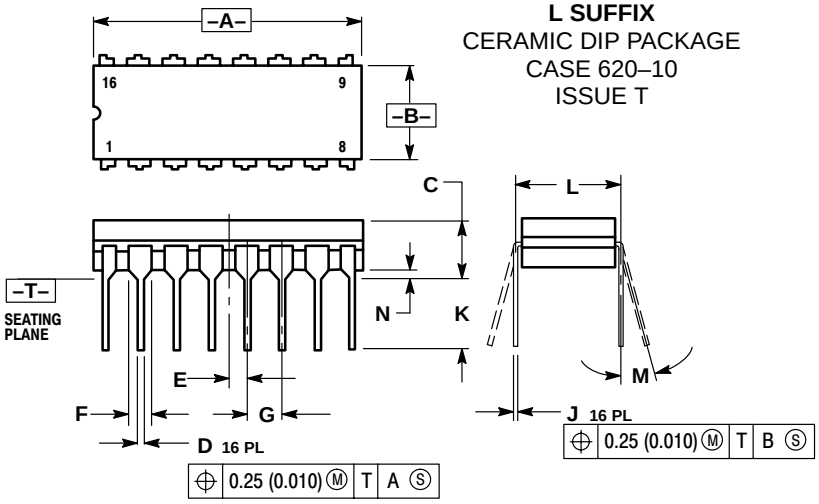


NOTES:
1. DATUMS –L–, –M–, AND –N– DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.
2. DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM –T–, SEATING PLANE.
3. DIMENSIONS R AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
4. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
5. CONTROLLING DIMENSION: INCH.
6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.385	0.395	9.78	10.03
B	0.385	0.395	9.78	10.03
C	0.165	0.180	4.20	4.57
E	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050 BSC		1.27 BSC	
H	0.026	0.032	0.66	0.81
J	0.020	---	0.51	---
K	0.025	---	0.64	---
R	0.350	0.356	8.89	9.04
U	0.350	0.356	8.89	9.04
V	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
X	0.042	0.056	1.07	1.42
Y	---	0.020	---	0.50
Z	2 °	10 °	2 °	10 °
G1	0.310	0.330	7.88	8.38
K1	0.040	---	1.02	---

PACKAGE DIMENSIONS

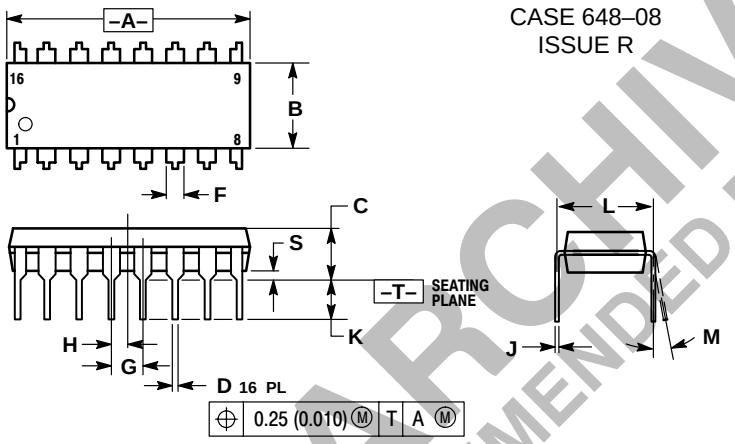
CDIP–16
L SUFFIX
CERAMIC DIP PACKAGE
CASE 620–10
ISSUE T



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.750	0.785	19.05	19.93
B	0.240	0.295	6.10	7.49
C	---	0.200	---	5.08
D	0.015	0.020	0.39	0.50
E	0.050 BSC		1.27 BSC	
F	0.055	0.065	1.40	1.65
G	0.100 BSC		2.54 BSC	
H	0.008	0.015	0.21	0.38
K	0.125	0.170	3.18	4.31
L	0.300 BSC		7.62 BSC	
M	0 °	15 °	0 °	15 °
N	0.020	0.040	0.51	1.01

PDIP–16
P SUFFIX
PLASTIC DIP PACKAGE
CASE 648–08
ISSUE R



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

Notes

Notes

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